

#### Silicon TVS Diode

 ESD / transient protection of data and power lines in low voltage applications according to:

IEC61000-4-2 (ESD): ± 25 kV (air) 20 kV (contact)

IEC61000-4-4 (EFT): 50 A / 2.5 kV (5/50 ns)

IEC61000-4-5 (surge): 5.5 A / 80 W (8/20 μs)

Small form factor (0402 inch):
 1.0 x 0.6 x 0.4 mm<sup>3</sup>

 Bi-directional, symmetrical working voltage up to ± 5.3 V

- Ultralow and symmetric clamping voltage
- ullet Ultralow dynamic resistance  ${\bf 0.4}~\Omega$
- Very fast response time
- Pb-free (RoHS compliant) package

#### **Applications**

Recommended to protect audio lines / microphone lines / speaker and headset systems in:

- Mobile phones
- Mobile TV
- Set top boxes
- MP3 players
- Minidisc players
- Portable entertainment electronics



#### ESD5V3S1B-02LRH



Туре	Package	Configuration	Marking
ESD5V3S1B-02LRH	TSLP-2-17	1 line, bi-directional	E1





**Maximum Ratings** at  $T_A = 25^{\circ}$ C, unless otherwise specified

Parameter	Symbol	Value	Unit
ESD air / contact discharge <sup>1)</sup>	V <sub>ESD</sub>	25 / 20	kV
Peak pulse current $(t_p = 8 / 20 \mu s)^2$	I <sub>pp</sub>	5.5	А
Peak pulse power ( $t_p = 8 / 20 \mu s^2$ )	$P_{pk}$	80	W
Operating temperature range	$T_{op}$	-55125	°C
Storage temperature	$T_{ m stg}$	-65150	

**Electrical Characteristics** at  $T_A = 25$ °C, unless otherwise specified

Parameter	Symbol	Values			Unit
		min.	typ.	max.	1
Characteristics					
Reverse working voltage	$V_{RWM}$	-5.3	-	5.3	V
Breakdown voltage	$V_{(BR)}$	6	-	-	
$I_{(BR)} = 1 \text{ mA}$	, ,				
Reverse current	I <sub>R</sub>	-	-	0.1	μΑ
$V_{R} = 3.3 \text{ V}$					
Clamping voltage	$V_{CL}$				V
$I_{PP} = 1 \text{ A}, t_p = 8/20 \ \mu\text{s}^{2)}$		-	8	10	
$I_{PP} = 3.5 \text{ A}, \ t_p = 8/20 \ \mu\text{s}^{2}$		-	10	12	
$I_{PP} = 5.5 \text{ A}, \ t_p = 8/20 \ \mu\text{s}^{2}$		-	11	13	
Diode capacitance	C <sub>T</sub>				pF
$V_{R} = 0 \text{ V}, f = 1 \text{ MHz}$		-	17.5	20	
$V_{R}$ = 2.5 V, $f$ = 1 MHz		_	14.5	-	
Dynamic resistance <sup>3)</sup> ( $t_D = 30 \text{ ns}$ )	$R_{D}$	-	0.4	-	Ω

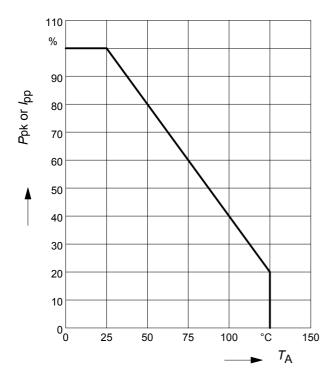
 $<sup>^{1}</sup>V_{\mbox{ESD}}$  according to IEC61000-4-2

 $<sup>^2</sup>I_{\mathrm{pp}}$  according to IEC61000-4-5

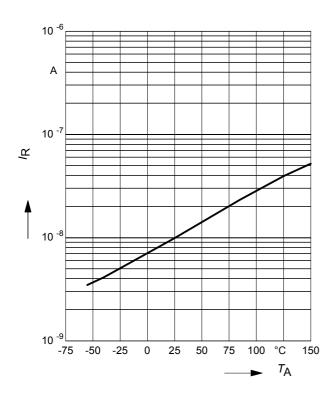
<sup>&</sup>lt;sup>3</sup> according to TLP tests



# Power derating curve $P_{pk} = f(T_A)$

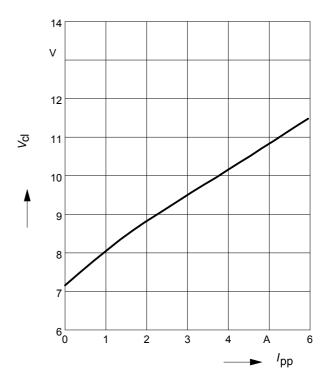


Reverse current  $I_R = f(T_A)$  $V_R = 3.3 \text{ V}$ 



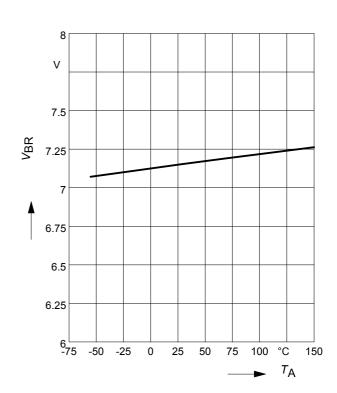
# Clamping voltage, $V_{\text{Cl}} = f(I_{\text{pp}})$

$$t_{\rm p}$$
 = 8 / 20 µs



# Breakdown voltage $V_{BR} = f(T_A)$

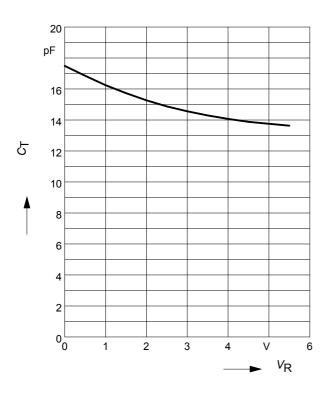
$$I_R = 1 \text{ mA}$$





# Diode capacitance $C_T = f(V_R)$

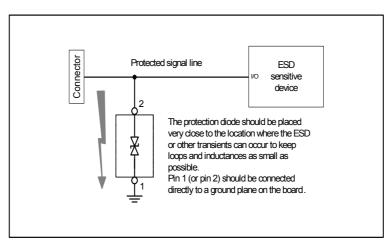
f = 1MHz





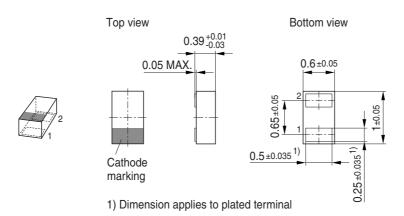
## **Application example**

single channel, bi-directional



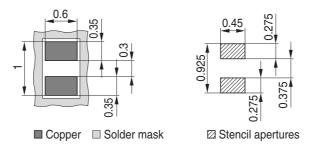


## Package Outline

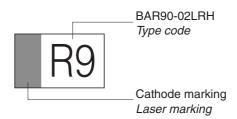


#### Foot Print

For board assembly information please refer to Infineon website "Packages"

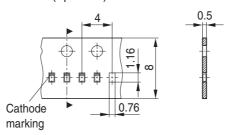


## Marking Layout (Example)



## Standard Packing

Reel ø180 mm = 15.000 Pieces/Reel Reel ø330 mm = 50.000 Pieces/Reel (optional)



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